

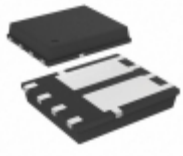

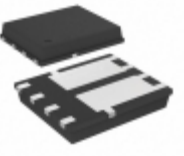

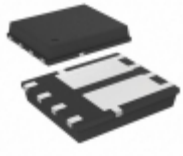

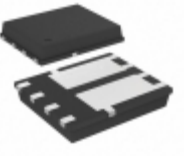
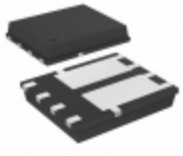
	<h2 style="color: red;">SI7844DP-T1-E3</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: SI7844DP-T1-E3
	Hersteller / Marke: Electro-Films (EFI) / Vishay
	Teil der Beschreibung: MOSFET 2N-CH 30V 6.4A PPAK SO-8
	Datenblätter:  SI7844DP-T1-E3.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 93250 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	SI7844DP-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET 2N-CH 30V 6.4A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	93250 pcs Stock
detaillierte Beschreibung	Mosfet Array 2 N-Channel (Dual) 30V 6.4A 1.4W
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.4W
Verpackung / Gehäuse	PowerPAK® SO-8 Dual
Supplier Device-Gehäuse	PowerPAK® SO-8 Dual
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6.4A
Rds On (Max) @ Id, Vgs	22 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	2.4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Cut Tape (CT)
Basisteilenummer	SI7844
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI7844DP-T1-E3CT

SI7844DP-T1-E3 ist neu im Original, Suche SI7844DP-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7844DP-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI7844DP-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7842DP-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 30V 6.3A PPAK SO-8</p>	 <p>SI7846DP-T1 VISHAY VISHAY QFN8</p>	 <p>SI7844DP-T1-E3 Vishay / Siliconix MOSFET 2N-CH 30V 6.4A PPAK SO-8</p>	 <p>SI7846DP-T1-E3 Vishay / Siliconix MOSFET N-CH 150V 4A PPAK SO-8</p>
 <p>SI7844DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 6.4A PPAK SO-8</p>	 <p>SI7844DP-T1 VISHAY SI7844DP-T1 VISHAY</p>	 <p>SI7842DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 6.3A PPAK SO-8</p>	 <p>SI7844DP-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 30V 6.4A PPAK SO-8</p>

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|---|--|--|---|---|
|  SI7812DN-T1-GE3 |  SI7812DN-T1-GE3 |  SI7818DN-T1-E3 |  SI7818DN-T1-E3 |  SI7820DN-T1-E3 |
|  SI7820DN-T1-E3 |  SI7820DN-T1-GE3 |  SI7820DN-T1-GE3 |  SI7840BDP |  SI7840BDP-T1-E3 |
|  SI7840BDP-T1-E3 |  SI7840BDP-T1-GE3 |  SI7840BDP-T1-GE3 |  SI7840DP |  SI7840DP-T1 |
|  SI7840DP-T1-E3 |  SI7840DP-T1-GE3 |  SI7840DP-T1-GE3. |  SI7842DP |  SI7842DP-T1-E3 |
|  SI7842DP-T1-E3 |  SI7842DP-T1-GE3 |  SI7842DP-T1-GE3 |  SI7844DP |  SI7844DP-T1 |
|  SI7844DP-T1-E3 |  SI7844DP-T1-GE3 |  SI7844DP-T1-GE3 |  SI7846DP |  SI7846DP-T1-E3 |
|  SI7846DP-T1-E3 |  SI7846DP-T1-GE3 |  SI7846DP-T1-GE3 |  SI7846DP-T1 |  SI7846SAC |
|  SI7848BDP-T1-E3 |  SI7848BDP-T1-E3 |  SI7848BDP-T1-GE3 |  SI7848BDP-T1-GE3 |  SI7848DP |
|  SI7848DP-T1-E3 |  SI7848DP-T1-GE3 |  SI7848DP-T1-GE3 |  SI7850DP |  SI7850DP-T1-E3 |
|  SI7850DP-T1-E3 |  SI7850DP-T1-GE3 |  SI7850DP-T1-GE3 |  SI7852ADP |  SI7852ADP-T1-E3 |

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